

MEDIUM POWER SINGLE BIPOLAR OPERATIONAL AMPLIFIER

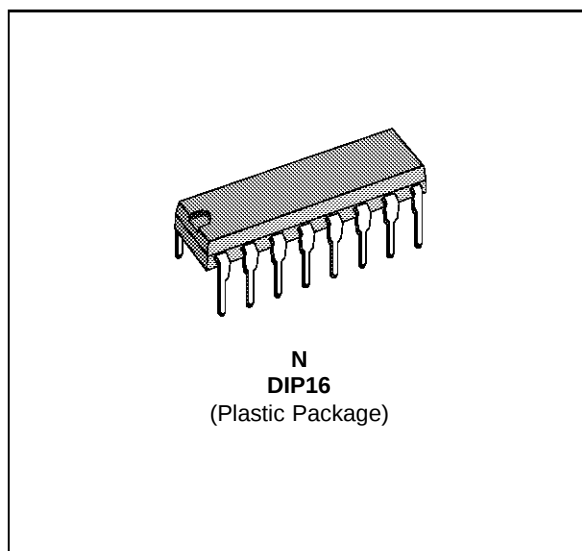
- OUTPUT CURRENT UP TO 500 mA
- OFFSET VOLTAGE NULL CAPABILITY
- SHORT-CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION
- PLASTIC PACKAGE FOR EASY ASSEMBLY

DESCRIPTION

The TDB7910 and TDA7910 are internally compensated medium power operational amplifiers intended for use in those applications requiring load currents of several hundred milliamperes. Applications include servo amplifiers, driver interfaces, precision power comparators and motor speed control.

These amplifiers are designed to operate from a single or dual power supplies and the input common-mode range includes the negative supply if balance inputs are tied to the negative supply.

The TDB7910 and TDA7910 are thermal overload and short-circuit protected.

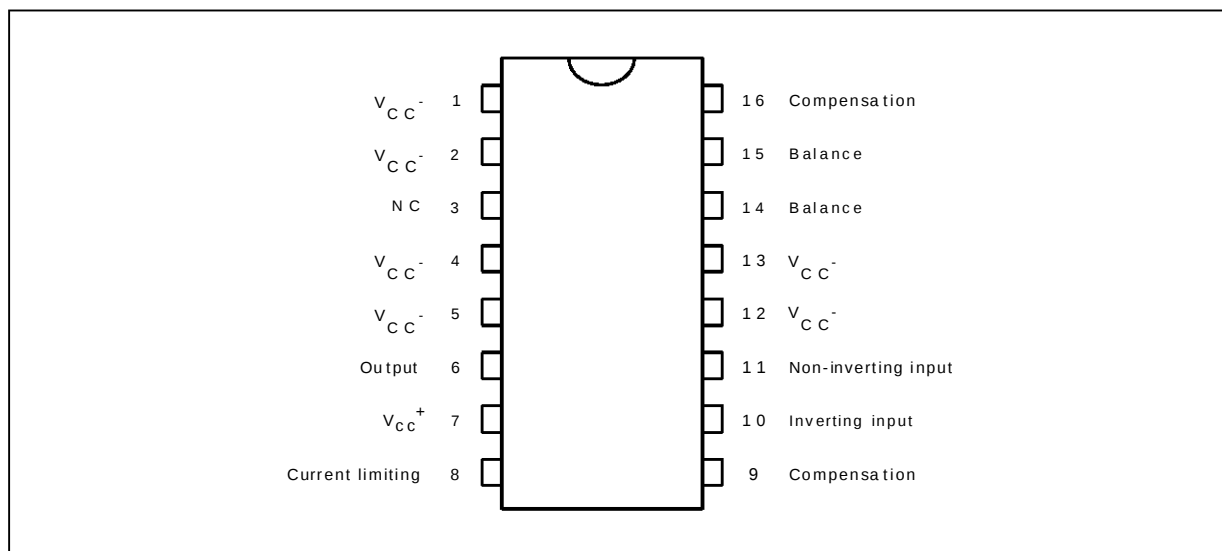


ORDER CODES

Part Number	Temperature Range	Package
		N
TDB7910	0°C, +70°C	•
TDA7910	-40°C, +105°C	•
Example : TDB7910N		

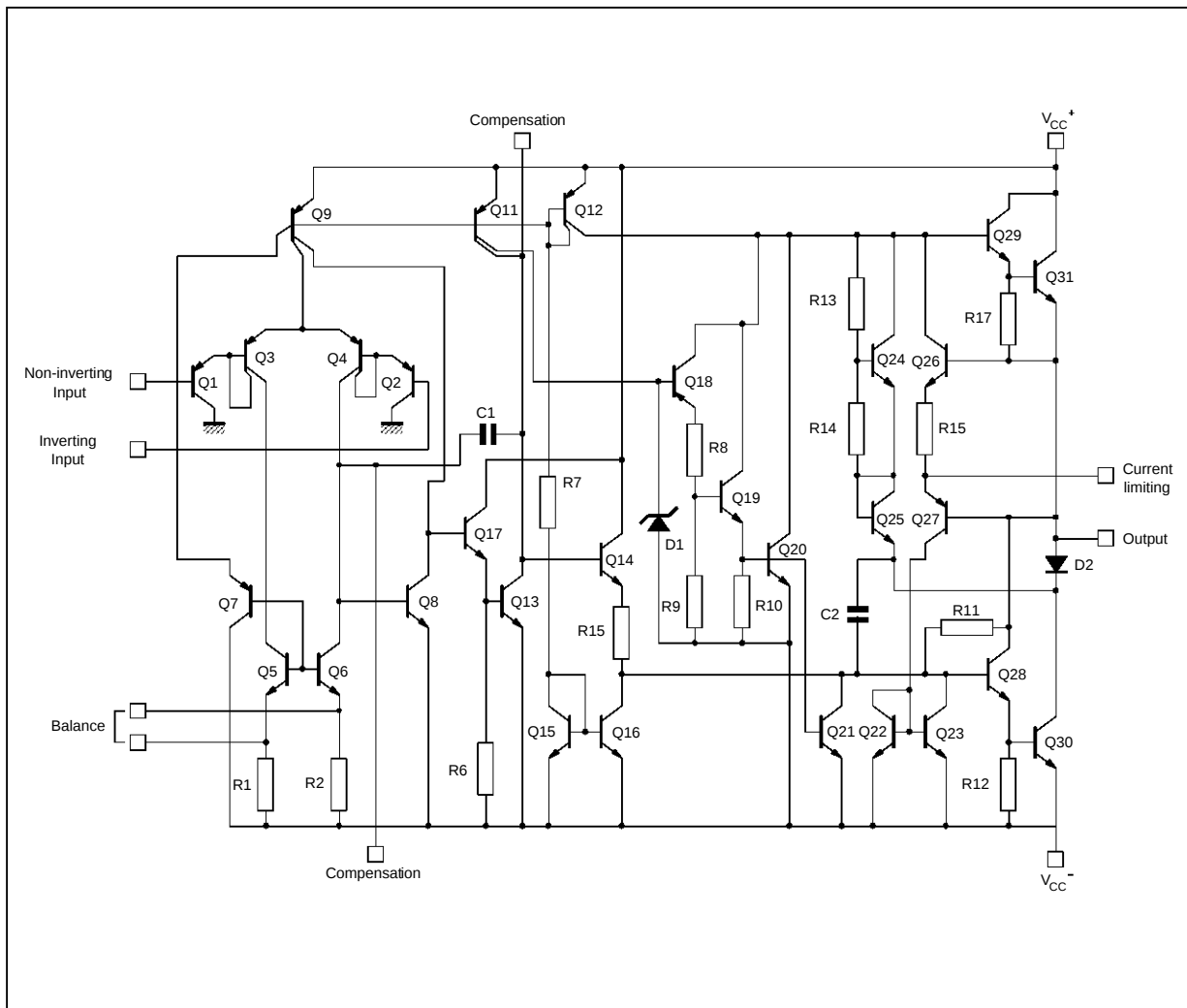
7910-01.TBL

PIN CONNECTIONS (top view)



7910-01.EPS

SCHEMATIC DIAGRAM



7910-02.EPS

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	± 18	V
V _i	Input Voltage	± 15	V
V _{id}	Differential Input Voltage	± 30	V
I _O	Output Current*	0.75	A
P _{tot}	Power Dissipation	7.5	W
T _{oper}	Operating Free-air Temperature Range	0 to +70 -40 to +105	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C

7910-02.TBL

* Under short-circuit conditions, the safe operating area and dc power dissipation limitations must be observed.

ELECTRICAL CHARACTERISTICSV_{CC} = ±15V, T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter	TDB7910 - TDA7910			Unit
		Min.	Typ.	Max.	
V _{io}	Input Offset Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		2	6 7.5	mV
I _{io}	Input Offset Current T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		20	200 300	nA
I _{ib}	Input Bias Current T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		80	500 800	nA
A _{vd}	Large Signal Voltage Gain (R _L = 47Ω, V _o = ±10V) T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	20 15			V/mV
I _{cc}	Supply Current - (no load) T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		10	20 25	mA
V _{icm}	Input Common Mode Voltage Range	±12	±13		V
I _{os}	Output Short Circuit Current (R _{SC} = 1.5Ω)		0.5		A
SVR	Supply Voltage Rejection Ratio	77			dB
CMR	Common Mode Rejection Ratio	70			dB
Z _i	Input Impedance	0.3			MΩ
V _{OPP}	Output Voltage Swing (R _{SC} = 0, R _L = 47Ω) T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	±11 ±10	±12		V
V _{ior}	Offset Voltage Adjustment Range		±15		mV
SR	Slew Rate (R _L = 47Ω, T _{amb} = +25°C, A _v = 1, V _{in} = ±10V)		0.5		V/μs
GBP	Gain Bandwidth Product (C _C = 0, R _L = 47Ω, C _L = 100pF, f = 100kHz, V _{in} = 10mV)		0.5		MHz
R _{TH}	Thermal Resistance		60		°C/W

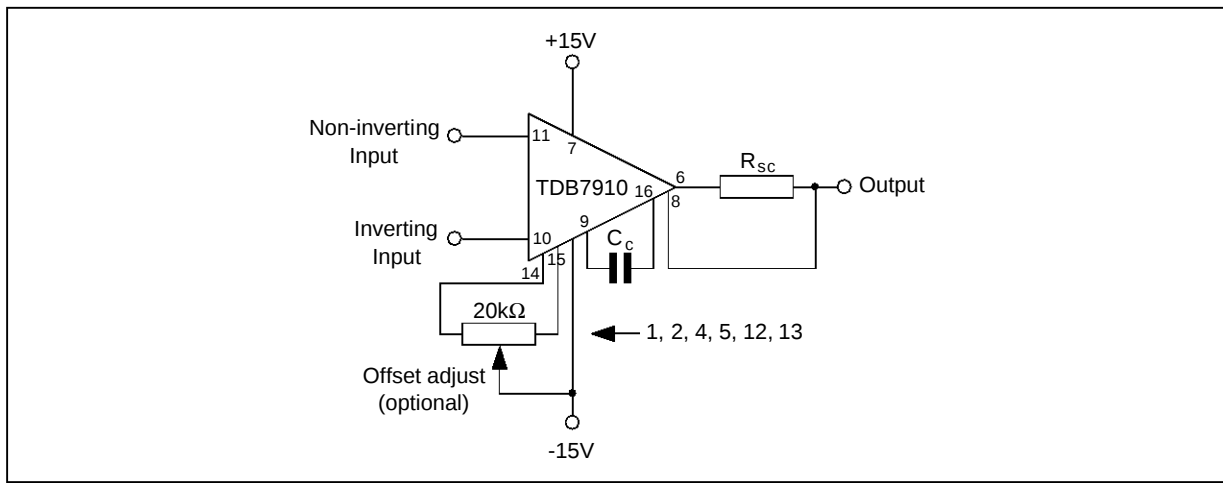
7910-03.TBL

ELECTRICAL CHARACTERISTICSV_{CC}⁺ = 10V, V_{CC}⁻ = 0V, T_{amb} = 25°C, V_o = +5V (unless otherwise specified)

Symbol	Parameter	TDB7910 - TDA7910			Unit
		Min.	Typ.	Max.	
V _{io}	Input Offset Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}			6 7.5	mV
A _{vd}	Large Signal Voltage Gain (R _L = 47Ω, V _o = 1 to 5V) T _{amb} = +25°C, T _{min.} ≤ T _{amb} ≤ T _{max.}	20 15			V/mV
I _{cc}	Supply Current - (no load) T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		5	20 25	mA
V _{OH}	High Level Output Voltage (R _{SC} = 0, R _L = 47Ω) T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	6 5	8		V
V _{OL}	Low Level Output Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		2	3 3	V
GBP	Gain Bandwidth Product (C _C = 0, R _L = 47Ω, C _L = 100pF, f = 100kHz, V _{in} = 10mV)		1		MHz

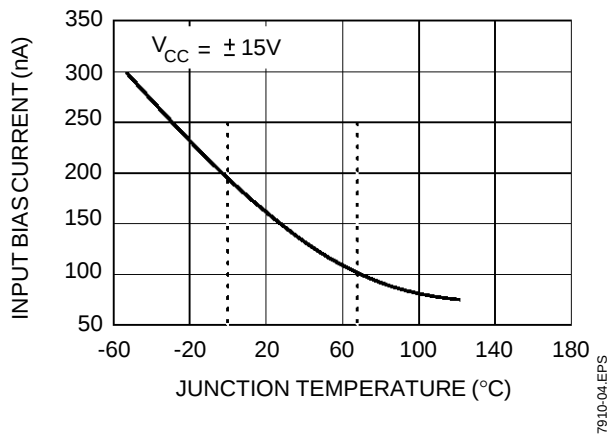
7910-04.TBL

BASIC DIAGRAM



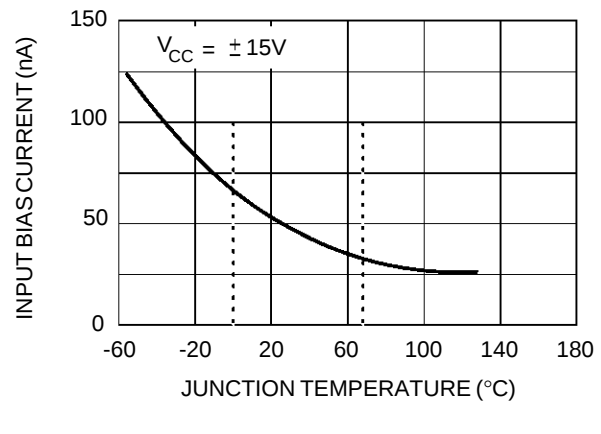
7910-03.EPS

INPUT BIAS CURRENT



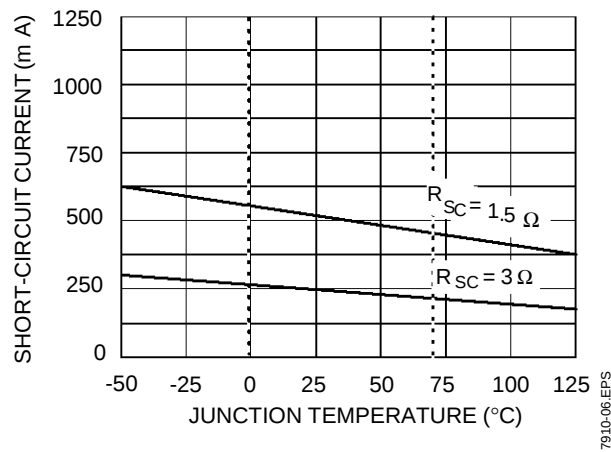
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INPUT OFFSET CURRENT



7910-05.EPS

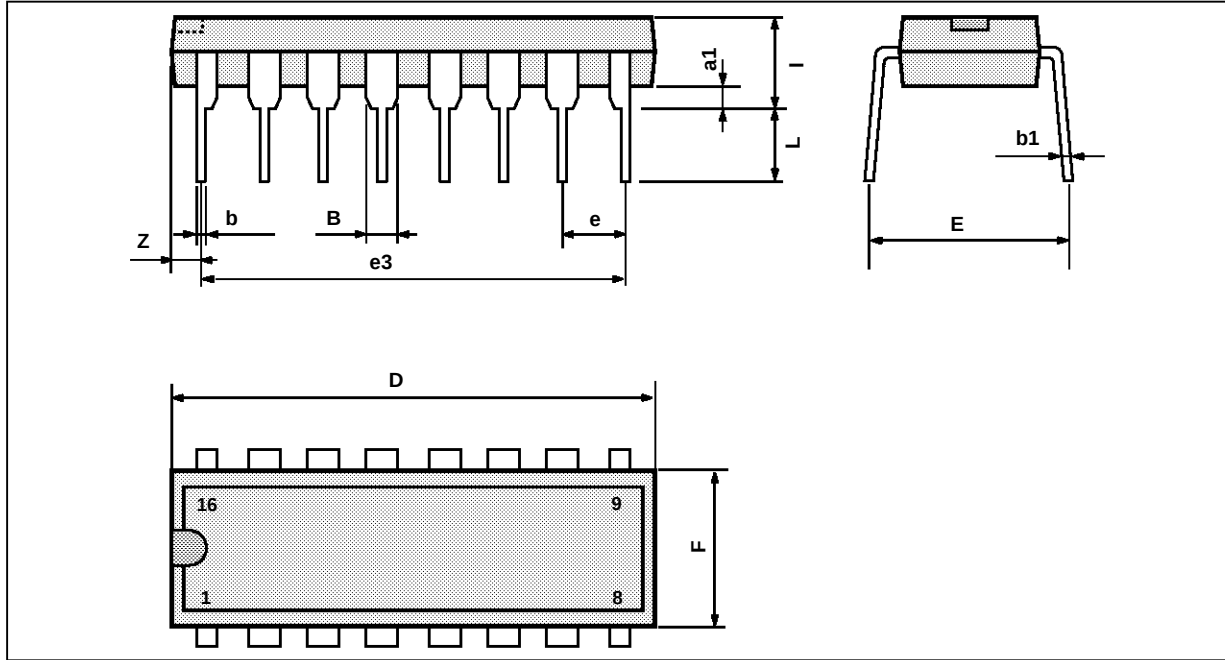
SHORT-CIRCUIT CURRENT



7910-06.EPS

PACKAGE MECHANICAL DATA

16 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

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